

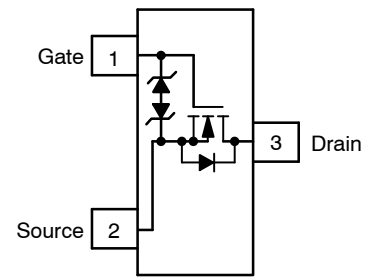
Features

- High density cell design for low $R_{DS(ON)}$
- Voltage controlled small signal switch
- Rugged and reliable
- High saturation current capability

Applications

- Load Switch for Portable Devices
- DC/DC Converter

Marking: KN



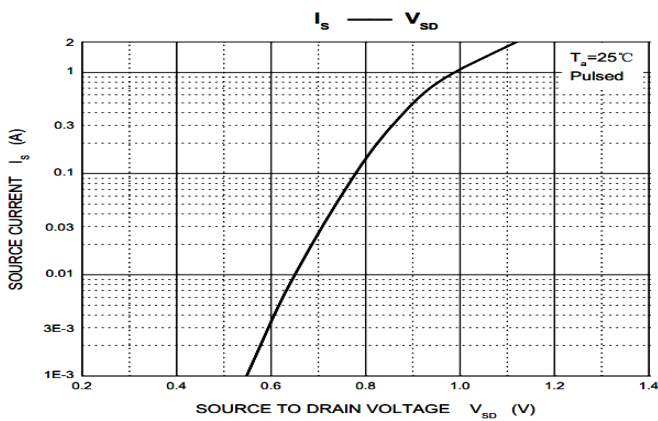
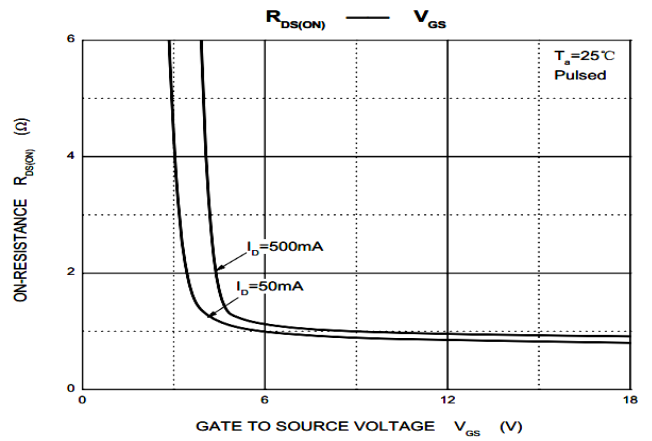
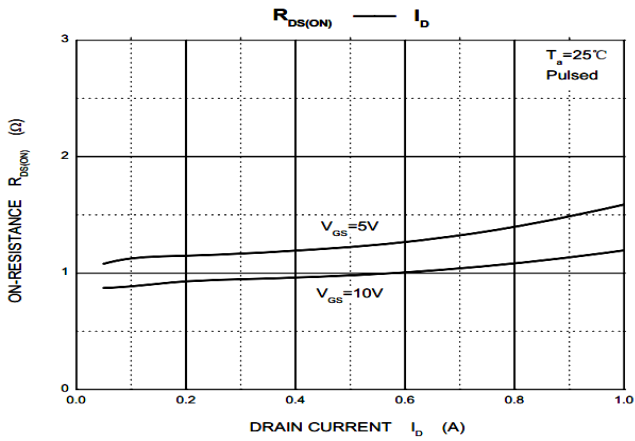
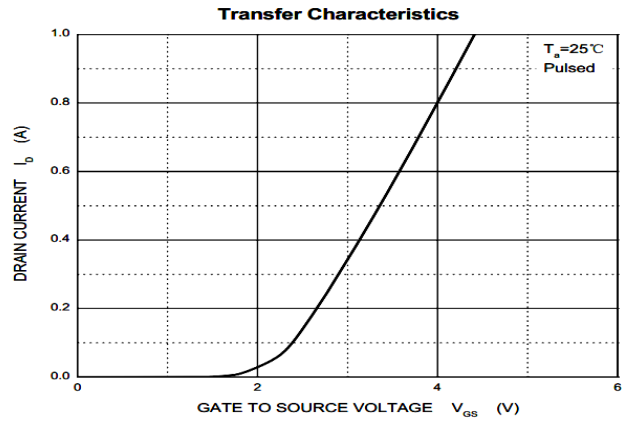
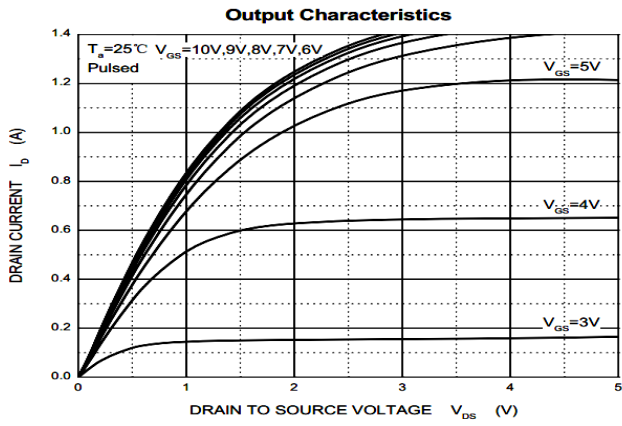
(Top View)

Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise specified)

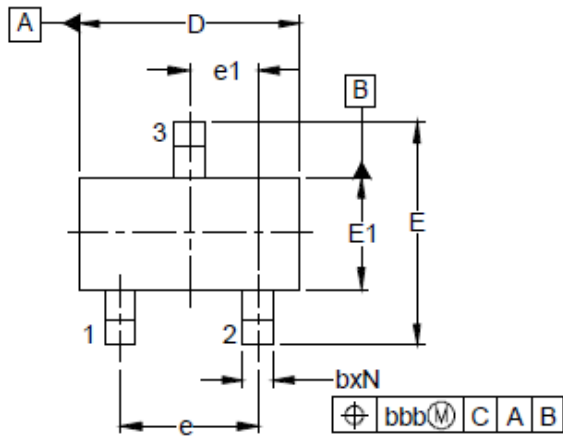
| Symbol | Parameter | Value | Unit |
|-----------------|---|-------------|---------------------------|
| V_{DS} | Drain-Source voltage | 60 | V |
| V_{GS} | Gate-Source voltage | 20 | V |
| I_D | Drain Current | 115 | mA |
| P_D | Power Dissipation | 150 | mW |
| $R_{\theta JA}$ | Thermal Resistance from Junction to Ambient | 833 | $^\circ\text{C}/\text{W}$ |
| T_J | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature | -55 to +150 | $^\circ\text{C}$ |

Electrical Characteristics ($T_a=25^\circ\text{C}$ unless otherwise specified)

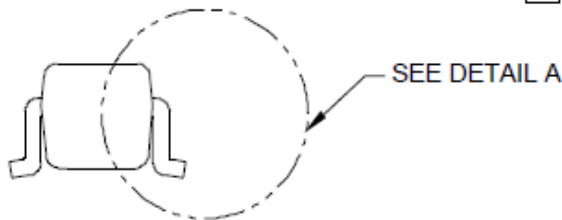
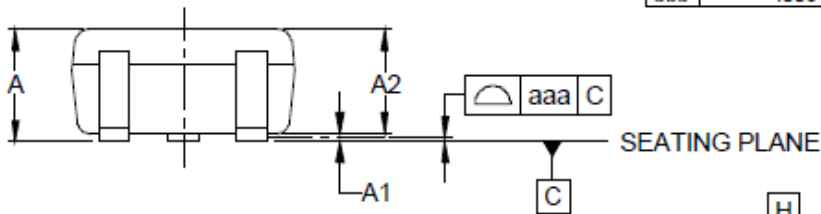
| Symbol | Parameter | Test Conditions | Min | Typ | Max | Unit |
|---------------|---------------------------------|---|------|-----|----------|----------|
| $V_{(BR)DSS}$ | Drain-Source Breakdown Voltage | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$ | 60 | | | V |
| $V_{GS(th)}$ | Gate-Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 1 | | 2.5 | V |
| I_{GSS} | Gate-body Leakage current | $V_{DS}=0\text{V}, V_{GS}=\pm 20\text{V}$ | | | ± 80 | nA |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS}=60\text{V}, V_{GS}=0\text{V}$ | | | 80 | nA |
| $I_{D(ON)}$ | On-state Drain Current | $V_{GS}=10\text{V}, V_{DS}=7\text{V}$ | 500 | | | mA |
| $R_{DS(on)}$ | Drain-Source On-Resistance | $V_{GS} = 10\text{V}, I_D = 500\text{mA}$ | | | 5 | Ω |
| | | $V_{GS} = 5\text{V}, I_D = 50\text{mA}$ | | | 7 | |
| g_{fs} | Forward Trans conductance | $V_{DS} = 10\text{V}, I_D = 200\text{mA}$ | 80 | | | mS |
| $V_{DS(on)}$ | Drain-source on-voltage | $V_{GS}=10\text{V}, I_D=500\text{mA}$ | | | 3.75 | V |
| | | $V_{GS}=5\text{V}, I_D=50\text{mA}$ | | | 0.375 | |
| V_{SD} | Diode Forward Voltage | $I_S=115\text{mA}, V_{GS}=0\text{V}$ | 0.55 | | 1.2 | V |
| C_{iss} | Input Capacitance | $V_{GS} = 0\text{V}$ | | | 50 | pF |
| C_{oss} | Output Capacitance | $V_{DS} = 25\text{V}$ | | | 25 | |
| C_{rss} | Reverse Transfer Capacitance | $f = 1.0\text{MHz}$ | | | 5 | |
| $t_{d(on)}$ | Turn-On Time | $V_{DD}=25\text{V}, R_L=50\Omega,$ $I_D=500\text{mA}, V_{GEN}=10\text{V},$ $R_G=25\Omega$ | | | 20 | ns |
| $t_{d(off)}$ | Turn-Off Time | | | | 40 | |



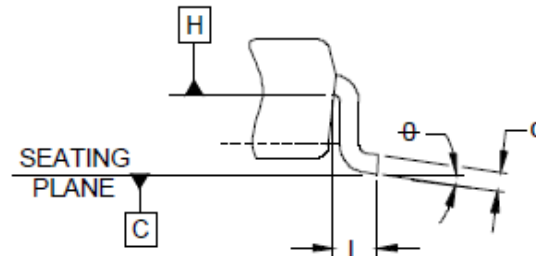
SOT-523 PACKAGE OUTLINE & DIMENSIONS



| DIM | INCHES | | | MILLIMETERS | | |
|----------|----------|------|------|-------------|------|------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | .023 | - | .035 | 0.60 | - | 0.90 |
| A1 | .000 | - | .004 | 0.00 | - | 0.10 |
| A2 | .023 | .030 | .031 | 0.60 | 0.75 | 0.80 |
| b | .005 | - | .012 | 0.15 | - | 0.30 |
| c | .003 | - | .008 | 0.10 | - | 0.20 |
| D | .059 | .063 | .067 | 1.50 | 1.60 | 1.70 |
| E | .057 | .063 | .069 | 1.45 | 1.60 | 1.75 |
| E1 | .029 | .031 | .033 | 0.75 | 0.80 | 0.85 |
| e | .039 BSC | | | 1.00 BSC | | |
| e1 | .020 BSC | | | 0.50 BSC | | |
| L | (.009) | | | (0.22) | | |
| N | 3 | | | 3 | | |
| θ | 0° | - | 8° | 0° | - | 8° |
| aaa | .004 | | | 0.10 | | |
| bbb | .008 | | | 0.20 | | |

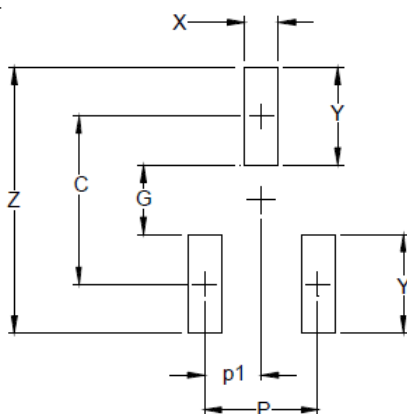


SIDE VIEW



DETAIL A

* SOLDERING FOOTPRINT



| DIM | DIMENSIONS | |
|-----|------------|-------------|
| | INCHES | MILLIMETERS |
| C | (.055) | (1.40) |
| P | .039 | 1.00 |
| p1 | .020 | 0.50 |
| G | .024 | 0.60 |
| X | .016 | 0.40 |
| Y | .031 | 0.80 |
| Z | .087 | 2.20 |